

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Round Through-Hole LED Lamp (3 mm)



OVLBx4C7 Series

- High brightness with well-defined spatial radiation patterns
- UV-resistant epoxy lens
- Lead-frame material is iron alloy with tin plated leads
- No stand-offs

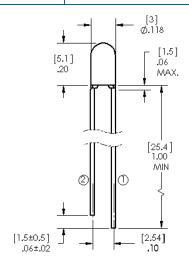


Each **OVLBx4C7** series device is a high-intensity LED mounted in a clear plastic T-1 package. The LED provides a well-defined and even emission pattern. Its UV-resistant epoxy lens makes this device an optimal solution for outdoor applications.

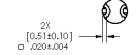
Applications

- Pedestrian signals
- Signage and architectural lighting
- Backlighting
- Automotive
- Outdoor/indoor displays

Part Number	Material	Emitted Color	Intensity Typ. mcd	Lens Color
OVLBB4C7	InGaN	Blue	1800	Clear
OVLBG4C7	IIIGain	Green	8400	Clear
OVLBR4C7	AllaCaP	Red	3700	Clear
OVLBY4C7	AllnGaP	Yellow	3700	Clear







① ANODE ② CATHODE

General tolerance +/- .25mm unless specified

Dimensions are in Inches [MM]

DO NOT LOOK DIRECTLY AT LED WITH UNSHIELDED EYES OR DAMAGE TO RETINA MAY OCCUR.



Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature Range	-40 ~ +100 ℃		
Operating Temperature Range		-40 ~ +100 ℃	
Reverse Voltage (Device not designed for reverse voltage applications)		5 V Max	
Continuous Famurant Comment (D. C.	Blue, Green	25 mA	
Continuous Forward Current (Design of heat dissipation should be considered)	Red, Yellow	50 mA	
Pools Forward Current (200 D. C. J. 4111)	Blue, Green	100 mA	
Peak Forward Current (10% Duty Cycle, 1 kHz)	Red, Yellow	100 mA	
Pawar Dissination	Blue, Green	100 mW	
Power Dissipation	Red, Yellow	120 mW	
Comment Linearity on Ambient Tenengurature	Blue, Green	-0.29 mA/°C	
Current Linearity vs Ambient Temperature	Red, Yellow	-0.72 mA/°C	
LED Junction Temperature		125°C	
Electrostatic Discharge Classification (JEDEC-JESD22-A114F)	Class 1C		
Lead Soldering Temperature (4 mm away from the base of the epoxy bulb)		260°C / 3 seconds	

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	COLOR	MIN	TYP	MAX	UNITS	CONDITIONS	
		Blue	1135	1800				
ı	Luminous Intensity	Green	4360	8400		mod	J 00 A	
I _V	Luminous intensity	Red	2225	3700		mcd	I _F = 20 mA	
		Yellow	2225	3700				
		Blue	2.6	3.2	4.0			
V _F	Forward Voltage	Green	2.0	3.2	4.0	V	I _F = 20 mA	
V F	Forward Vollage	Red	1.8	2.0	2.4] v		
		Yellow	2.0	2.4				
		Blue			- 10 μΑ		V _R = 5 V	
I_	Reverse Current	Green						
I _R	neverse Guirein	Red				μΑ	V _R = 3 V	
		Yellow						
		Blue	460	470	475			
,	Dominant Wavelength	Green	519	525	531	nm	1 20 mA	
λ_{D}		Red	620	623	630	nm	I _F = 20 mA	
		Yellow	585	589	595			
20½H-H	50% Power Angle			45		deg	$I_F = 20 \text{ mA}$	



Standard Bins

LEDs are sorted to luminous intensity (I_V) , forward voltage (V_F) and dominant wavelength (nm) bins listed below. Each bag consists of a single intensity bin, single voltage bin and a single color bin. Orders are filled using all intensity and color bins listed in the following tables. Optek will not accept orders for single intensity bins, single voltage bins or single color bins.

Luminous Intensity (I_V) @ 20mA

	Blue: OVLBB4C7					
. ,	, ,					
1,135	1,590					
1,590	2,225					
2,225	3,115					
3,115	4,360					
en: OVLBG4	C7					
Min (mcd)	Max (mcd)					
4,360	6,105					
6,105	8,550					
8,550	11,970					
11,970	16,758					
	2,225 3,115 een: OVLBG4 Min (mcd) 4,360 6,105 8,550					

Forward Voltage (V_F)

Blue: OVLBB4C7 & Green: OVLBG4C7					
VF Code	Min	Max			
Α	2.6	2.8			
В	2.8	3.0			
С	3.0	3.2			
D	3.2	3.4			
E	3.4	3.6			
F	3.6	3.8			
G	3.8	4.0			

Dominant Wavelength (nm)

Blue: OVLBB4C7						
nm Code Min Max						
ВС	460	465				
BD	465	470				
BE	470	475				
,						
Green: OVLBG4C7						
nm Code	Min	Max				
FB	519	523				
FC	523	527				
FD	527	531				

Luminous Intensity (I_V) @ 20mA

Red: OVLBR4C7					
IV Code	Min (mcd)	Max (mcd)			
0U	2,225	3,115			
0V	3,115	4,360			
0W	4,360	6,105			
Yel	Yellow: OVLBY4C7				
IV Code	Min (mcd)	Max (mcd)			
0U	2,225	3,115			
0V	3,115	4,360			
0W	4,360	6,105			

Forward Voltage (V_F)

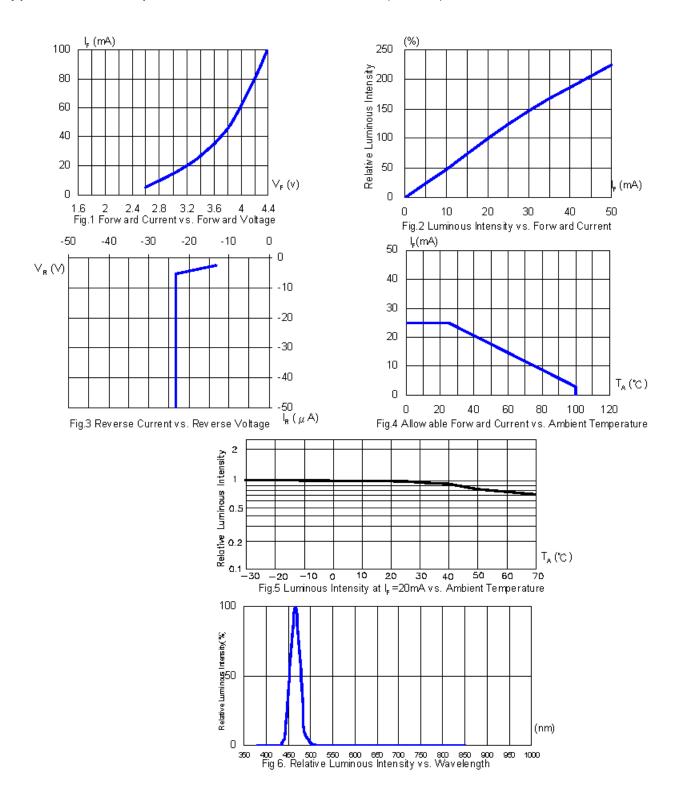
Red: OVLBR4C7 & Yellow: OVLBY4C7				
VF Code Min Max				
Α	1.8	2.0		
В	2.0	2.2		
С	2.2	2.4		

Dominant Wavelength (nm)

Red: OVLBR4C7					
Min	Max				
620	625				
625	630				
Yellow: OVLBY4C7					
Min	Max				
585	587				
587	589				
589	591				
591	593				
593	595				
	Min 620 625 low: OVLBY4 Min 585 587 589				

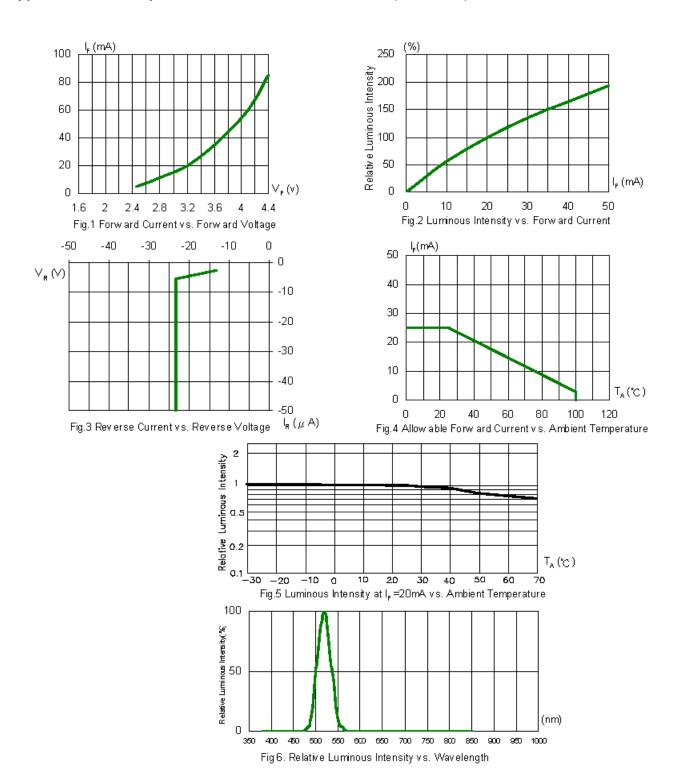


Typical Electro-Optical Characteristics Curves (BLUE)



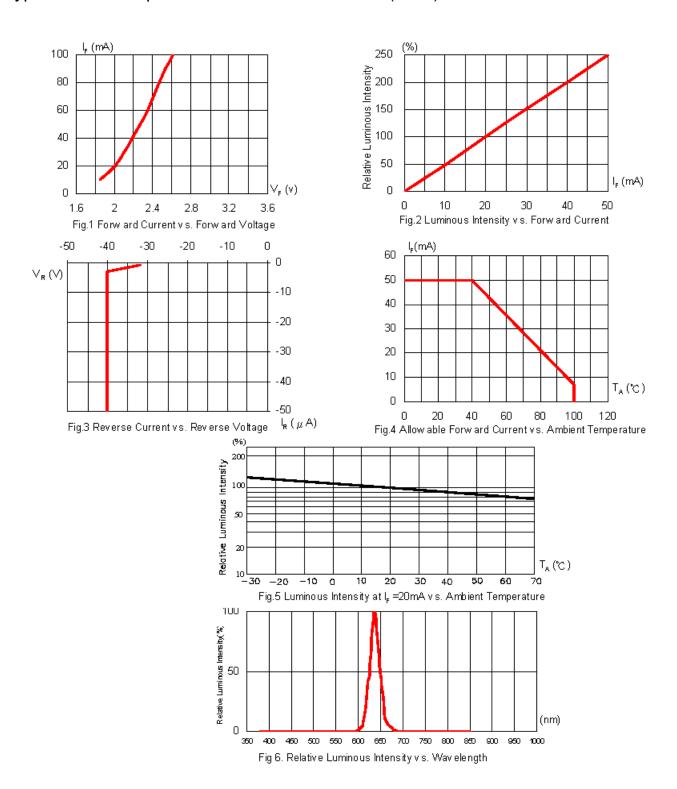


Typical Electro-Optical Characteristics Curves (GREEN)



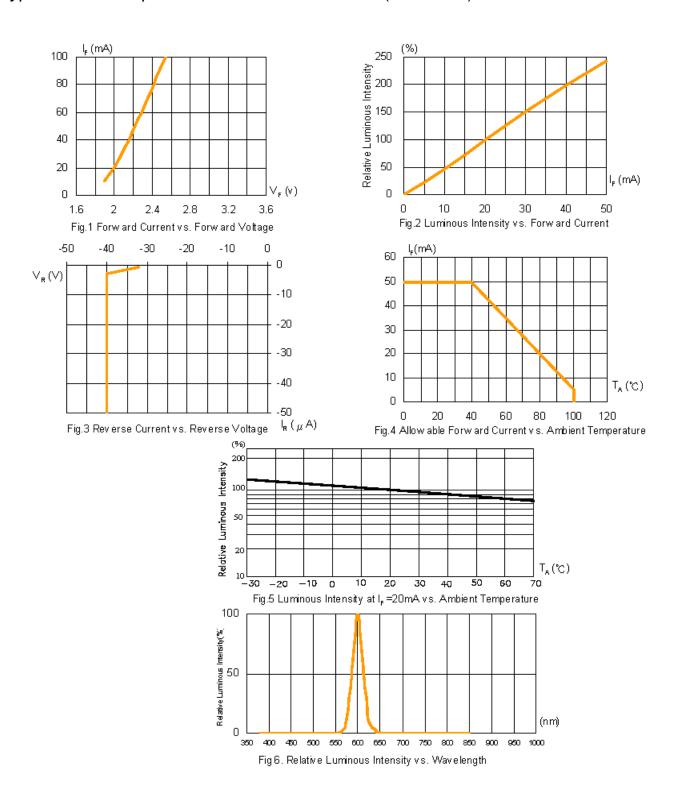


Typical Electro-Optical Characteristics Curves (RED)





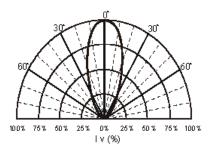
Typical Electro-Optical Characteristics Curves (YELLOW)



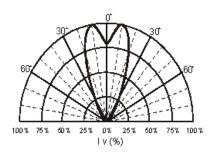


Beam Pattern:

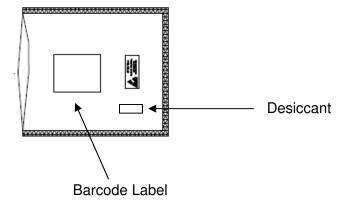
(Blue) and (Green)



(Red) and (Yellow)



Packaging: 500 pcs per bulk bag with desiccant





Reliability Test

LED lamps are checked by reliability tests based on MIL standards.

Classi- fication	Test Item	Standard Test Method	Test Conditions	Duration	Unit	Acc / Rej Criteria	Result
Life Test	Operation Life Test (OLT)	MIL-STD-750D Method 1026.3	$T_A=25^{\circ}C$, $I_F=30\text{mA}$ *	1000 Hrs	100	0 / 1	Pass
	High Temperature Storage (HTS)	MIL-STD-750D Method 1032.1	T _A =100°C	1000 Hrs	100	0 / 1	Pass
Test	Low Temperature Storage (LTS)	MIL-STD-750D Method 1032.1	T _A =-40°C	1000 Hrs	100	0 / 1	Pass
Environment Test	Temp. & Humidity with Bias (THB)	MIL-STD-750D Method 103B	T _A =85°C , Rh=85% I _F =20mA **	500 Hrs	100	0 / 1	Pass
Envii	Thermal Shock Test (TST)	MIL-STD-750D Method 1056.1	0°C ~ 100°C 2min 2min	100 cycles	100	0 / 1	Pass
	Temperature Cycling Test (TCT)	MIL-STD-750D Method 1051.5	-40°C ~ 25°C ~ 100°C ~ 25°C 30min 5min 30min 5min	100 cycles	100	0 / 1	Pass
Test	Solderability	MIL-STD-750D Method 2026.4	235±5℃ , 5 sec	1 time	20	0 / 1	Pass
Mechanical Test	Resistance to Soldering Heat	MIL-STD-750D Method 2031.1	260±5℃,10 sec	1 time	20	0 / 1	Pass
Мес	Lead Integrity	MIL-STD-750D Method 2036.3	Load 2.5N (0.25kgf) $0^{\circ} \sim 90^{\circ} \sim 0^{\circ}$, bend	3 times	20	0 / 1	Pass

Remark : (*) $I_F = 30$ mA for AlInGaP chip ; $I_F = 20$ mA for InGaN chip (**) $I_F = 20$ mA for AlInGaP chip ; $I_F = 10$ mA for InGaN chip

2. Failure Criteria (T_A =25°ℂ):

Test Item	Test Item Symbol Test O		Criteria for Judgment			
rest item	Symbol	Test Conditions	Min.	Max.		
Luminous Intensity	$I_{ m V}$	I _F =20 mA	LSL×0.7 **			
Voltage (Forward)	V_{F}	I _F =20 mA		USL×1.1 *		

(*) USL : Upper Standard Level , (**) LSL : Lower Standard Level